

Electrolyte-Gated Organic Field-Effect Transistor

An Electrolyte-Gated Organic Field-Effect Transistor, for short EGOFET, is a type of field-effect transistor where the gate dielectric layer is replaced by an electrolyte and the semiconductor is an organic material. Just like a traditional field-effect transistor, an EGOFET comprises tree electrodes, including source, drain, and gate electrode.

In an EGOFET constructed with a p-type organic semiconductor, the gate is negatively polarized, causing the positive ions of the electrolyte to accumulate at the gate-electrolyte interface. Concurrently, the negative ions accumulate at the electrolyte-organic semiconductor interface. This ends up in the formation of electrical double layer at the two aforementioned interfaces.

In this example, we are going to show how to model the static characteristics of this device based on a general Drift-Diffusion model.

Model Definition

The materials and geometry of this model are a simplified version of the device described in Ref. 1. The model uses the following configuration: source and drain electrodes positioned on the two side ends of the organic semiconductor domain and the gate electrode placed at the top boundary of the electrolyte domain. The total depth of the transistor is 1 cm with a width of 30 µm. Figure 1 shows the configuration of the modeled device.

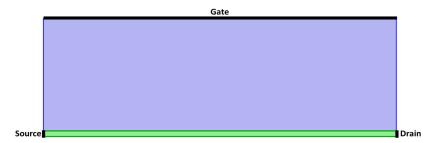


Figure 1: Configuration of the modeled EGOFET, with the organic semiconductor domain in green and the electrolyte in blue.

In a p-type organic semiconductor, the charge carriers are holes, while in the electrolyte domain, ions serve as the charge carriers. The model uses the Stabilized Convection— Diffusion Equation interface for defining transport phenomena (Equation 1) and the

Electrostatics interface to describe the motion of the charges under the applied electric field (Equation 2):

$$\nabla \cdot J_c = \nabla \cdot \left(-D_c \nabla c - z_c \frac{D_c}{RT} F c \nabla V \right) = 0 \tag{1}$$

$$-\nabla \cdot (\varepsilon_0 \varepsilon_r \nabla V) = c \times F \tag{2}$$

In the equations above, J_c , D_c , and z_c , are flux, diffusion coefficient, and charge of the charge carriers, respectively. R is the ideal gas constant, T the temperature, F the Faraday constant, and V the electric potential. ε_0 and ε_r are the permittivity of vacuum and relative permittivity of the material, respectively.

Since there are three different types of charge carriers in this device, we use the same set of equations for each, namely the holes, positive ions and negative ions. The procedure of the implementation is described in detail in the Modeling Instructions section.

Results and Discussion

Figure 2 shows the electric field profile at the cross-section of the device (along the y direction) for zero drain voltage and gate voltage varying from 0 to -0.5 V. The profile shows a high electric field at the two interfaces, corresponding to the gate–electrolyte and electrolyte–organic semiconductor interface. This is due to the accumulation of charges at these interfaces.

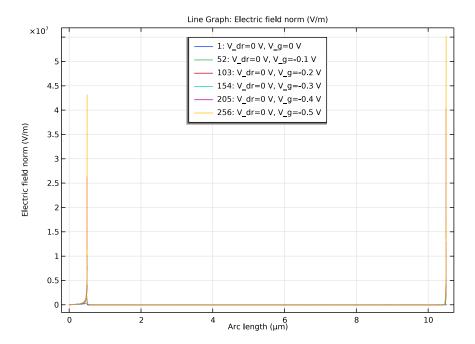


Figure 2: Electric field along the cross section of the EGOFET.

Figure 3 shows the transfer curve of the EGOFET which is drain current versus the gate voltage.

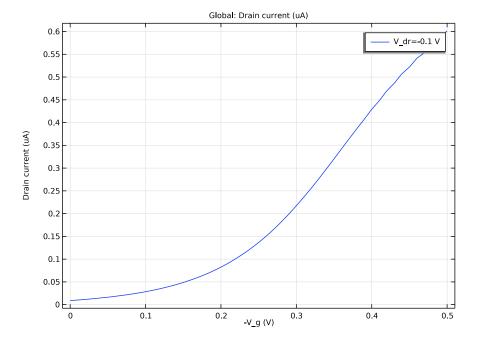


Figure 3: Drain current versus gate voltage curve.

Reference

1. N. Delavari, K. Tybrandt, M. Berggren, B. Piro, V. Noël, G.Mattana, and I. Zozoulenko, "Nernst-Planck-Poisson analysis of electrolyte-gated organic field-effect transistors," J. Phys. D: Appl. Phys., vol. 54, no. 41, 415101, 2021.

Application Library path: Semiconductor_Module/Transistors/egofet

Modeling Instructions

From the File menu, choose New.

NEW

In the New window, click Model Wizard.

MODEL WIZARD

- I In the Model Wizard window, click **2** 2D.
- 2 In the Select Physics tree, select Mathematics>Classical PDEs>Stabilized Convection-Diffusion Equation (scdeq).
- 3 Click Add.
- 4 In the Select Physics tree, select Mathematics>Classical PDEs>Stabilized Convection-Diffusion Equation (scdeq).
- 5 Click Add.
- 6 In the Select Physics tree, select Mathematics>Classical PDEs>Stabilized Convection-Diffusion Equation (scdeq).
- 7 Click Add.
- 8 In the Select Physics tree, select AC/DC>Electric Fields and Currents>Electrostatics (es).
- 9 Click Add.
- 10 Click Study.
- II In the Select Study tree, select General Studies>Stationary.
- 12 Click Done.

GLOBAL DEFINITIONS

Parameters 1

- I In the Model Builder window, under Global Definitions click Parameters I.
- 2 In the Settings window for Parameters, locate the Parameters section.
- **3** In the table, enter the following settings:

Name	Expression	Value	Description
w_dom	30[um]	3E-5 m	Domain width
h_semi	500[nm]	5E-7 m	Organic semiconductor thickness
h_electrolyte	10[um]	1E-5 m	Electrolyte thickness
V_dr	0[V]	0 V	Drain electrode Voltage
V_g	0[V]	0 V	Gate electrode voltage

Name	Expression	Value	Description
D_ch	1e-6[m^2/s]	IE-6 m ² /s	Diffusion coefficient for holes
D_c	15e-10[m^2/s]	1.5E-9 m ² /s	Diffusion coefficient for ions
Т	300[K]	300 K	Temperature
d	1[cm]	0.01 m	depth
z_ch	+1	1	charge of hole
z_cp	+1	I	charge of positive ions
z_cn	- 1	-1	charge of negative ions
ch0	1e-3[mol/m^3]	0.001 mol/m ³	Holes initial concentration
ср0	1[mol/m^3]	I mol/m³	Positive ions initial concentration
cn0	1[mol/m^3]	I mol/m³	Negative ions initial concentration

GEOMETRY I

- I In the Model Builder window, expand the Component I (compl)>Geometry I node, then click Geometry I.
- 2 In the Settings window for Geometry, locate the Units section.
- 3 From the Length unit list, choose μm .

Rectangle I (r1)

- I In the Geometry toolbar, click Rectangle.
- 2 In the Settings window for Rectangle, locate the Size and Shape section.
- 3 In the Width text field, type w_dom.
- 4 In the **Height** text field, type h_semi.
- 5 Right-click Rectangle I (rI) and choose Duplicate.

Rectangle 2 (r2)

- I In the Model Builder window, click Rectangle 2 (r2).
- 2 In the Settings window for Rectangle, locate the Size and Shape section.

- 3 Clear the Height text field.
- 4 Locate the **Position** section. In the y text field, type h semi.
- 5 Locate the Size and Shape section. In the Height text field, type h electrolyte.
- 6 Click Build All Objects.

DEFINITIONS

Integration I (intob1)

- I In the **Definitions** toolbar, click Nonlocal Couplings and choose Integration.
- 2 In the Settings window for Integration, locate the Source Selection section.
- 3 From the Geometric entity level list, choose Boundary.
- 4 Click Paste Selection.
- 5 In the Paste Selection dialog box, type 6 in the Selection text field.
- 6 Click OK.
- 7 In the Settings window for Integration, locate the Advanced section.
- 8 From the Method list, choose Summation over nodes.

Variables 1

- I In the Model Builder window, right-click Definitions and choose Variables.
- 2 In the Settings window for Variables, locate the Variables section.
- **3** In the table, enter the following settings:

Name	Expression	Unit	Description
I_dr	<pre>intop1(-reacf(ch))[mol/(m*s)]* F_const*d</pre>		Drain current

DRIFT-DIFFUSION EQUATION FOR HOLES

- I In the Model Builder window, under Component I (compl) click Stabilized Convection-Diffusion Equation (scdeq).
- 2 In the Settings window for Stabilized Convection-Diffusion Equation, type Drift-Diffusion Equation for Holes in the Label text field.
- 3 Locate the **Domain Selection** section. In the list, select **2**.
- 4 Click Remove from Selection.
- **5** Select Domain 1 only.
- 6 Locate the Units section. Click Define Dependent Variable Unit.

7 In the Dependent variable quantity table, enter the following settings:

Dependent variable quantity	Unit
Custom unit	mol/m^3

- 8 Click Define Source Term Unit.
- **9** In the **Source term quantity** table, enter the following settings:

Source term quantity	Unit
Custom unit	mol/(m^3*s)

10 Click to expand the **Dependent Variables** section. In the **Dependent variable (mol/m³)** text field, type ch.

Convection-Diffusion Equation 1

- I In the Model Builder window, under Component I (compl)>Drift-Diffusion Equation for Holes (scdeq) click Convection-Diffusion Equation I.
- 2 In the Settings window for Convection-Diffusion Equation, locate the Diffusion Coefficient section.
- 3 In the c text field, type D ch.
- 4 Click to expand the Conservative Flux Convection Coefficient section. Specify the α vector as

5 Click to collapse the **Convection Coefficient** section. Locate the **Source Term** section. In the *f* text field, type 0.

Initial Values 1

- I In the Model Builder window, click Initial Values I.
- 2 In the Settings window for Initial Values, locate the Initial Values section.
- 3 In the ch text field, type ch0.

No Flux I

- I In the Physics toolbar, click
 Boundaries and choose No Flux.
- 2 In the Settings window for No Flux, locate the Boundary Selection section.
- 3 From the Selection list, choose All boundaries.

Dirichlet Boundary Condition I

- I In the Physics toolbar, click Boundaries and choose Dirichlet Boundary Condition.
- 2 In the Settings window for Dirichlet Boundary Condition, locate the Boundary Selection section.
- 3 Click Paste Selection.
- 4 In the Paste Selection dialog box, type 1 6 in the Selection text field.
- 5 Click OK.
- 6 In the Settings window for Dirichlet Boundary Condition, locate the Value on Boundary section.
- 7 In the r text field, type ch0.

DRIFT-DIFFUSION EQUATION FOR POSITIVE IONS

- I In the Model Builder window, under Component I (compl) click Stabilized Convection-Diffusion Equation 2 (scdeq2).
- 2 In the Settings window for Stabilized Convection-Diffusion Equation, type Drift-Diffusion Equation for Positive Ions in the Label text field.
- 3 Locate the **Domain Selection** section. In the list, select 1.
- 4 Click Remove from Selection.
- **5** Select Domain 2 only.
- 6 Locate the Units section. Click Define Dependent Variable Unit.
- 7 In the Dependent variable quantity table, enter the following settings:

Dependent variable quantity	Unit
Custom unit	mol/m^3

- 8 Click Define Source Term Unit.
- **9** In the **Source term quantity** table, enter the following settings:

Source term quantity	Unit
Custom unit	mol/(m^3*s)

10 Locate the Dependent Variables section. In the Dependent variable (mol/m³) text field, type cp.

Convection-Diffusion Equation 1

I In the Model Builder window, under Component I (compl)>Drift-Diffusion Equation for Positive Ions (scdeq2) click Convection-Diffusion Equation 1.

- 2 In the Settings window for Convection-Diffusion Equation, locate the Diffusion Coefficient section.
- **3** In the c text field, type D_c.
- **4** Locate the **Conservative Flux Convection Coefficient** section. Specify the α vector as

5 Locate the **Source Term** section. In the f text field, type **0**.

Initial Values 1

- I In the Model Builder window, click Initial Values I.
- 2 In the Settings window for Initial Values, locate the Initial Values section.
- **3** In the cp text field, type cp0.

No Flux I

- I In the Physics toolbar, click Boundaries and choose No Flux.
- 2 In the Settings window for No Flux, locate the Boundary Selection section.
- 3 From the Selection list, choose All boundaries.

Dirichlet Boundary Condition I

- I In the Physics toolbar, click Boundaries and choose Dirichlet Boundary Condition.
- 2 Click the **Zoom Extents** button in the **Graphics** toolbar.
- **3** Select Boundaries 3 and 7 only.
- 4 In the Settings window for Dirichlet Boundary Condition, locate the Value on Boundary section.
- **5** In the r text field, type cp0.

DRIFT-DIFFUSION EQUATION FOR NEGATIVE IONS

- I In the Model Builder window, under Component I (compl) click Stabilized Convection-Diffusion Equation 3 (scdeq3).
- 2 In the Settings window for Stabilized Convection-Diffusion Equation, type Drift-Diffusion Equation for Negative Ions in the Label text field.
- 3 Locate the **Domain Selection** section. In the list, select 1.
- 4 Click Remove from Selection.
- **5** Select Domain 2 only.
- 6 Locate the Units section. Click Define Dependent Variable Unit.

7 In the Dependent variable quantity table, enter the following settings:

Dependent variable quantity	Unit
Custom unit	mol/m^3

- 8 Click Define Source Term Unit.
- **9** In the **Source term quantity** table, enter the following settings:

Source term quantity	Unit
Custom unit	mol/(m^3*s)

10 Locate the Dependent Variables section. In the Dependent variable (mol/m³) text field, type cn.

Convection-Diffusion Equation 1

- I In the Model Builder window, under Component I (comp1)>DriftDiffusion Equation for Negative Ions (scdeq3) click Convection-Diffusion Equation I.
- 2 In the Settings window for Convection-Diffusion Equation, locate the Diffusion Coefficient section.
- **3** In the c text field, type D c.
- **4** Locate the Conservative Flux Convection Coefficient section. Specify the α vector as

5 Locate the **Source Term** section. In the f text field, type **0**.

Initial Values 1

- I In the Model Builder window, click Initial Values I.
- 2 In the Settings window for Initial Values, locate the Initial Values section.
- 3 In the cn text field, type cn0.

No Flux I

- I In the Physics toolbar, click Boundaries and choose No Flux.
- 2 In the Settings window for No Flux, locate the Boundary Selection section.
- 3 From the Selection list, choose All boundaries.

Dirichlet Boundary Condition I

- I In the Physics toolbar, click Boundaries and choose Dirichlet Boundary Condition.
- **2** Select Boundaries 3 and 7 only.

- 3 In the Settings window for Dirichlet Boundary Condition, locate the Value on Boundary section.
- 4 In the r text field, type cn0.

ELECTROSTATICS (ES)

- I In the Model Builder window, under Component I (compl) click Electrostatics (es).
- 2 In the Settings window for Electrostatics, locate the Thickness section.
- 3 In the d text field, type d.
- **4** Click to expand the **Dependent Variables** section.

Charge Conservation 1

- I In the Model Builder window, under Component I (compl)>Electrostatics (es) click Charge Conservation I.
- 2 In the Settings window for Charge Conservation, locate the Domain Selection section.
- 3 In the list, select 2.
- 4 Locate the Constitutive Relation D-E section. From the ε_r list, choose User defined. Locate the Domain Selection section. In the list, select 1.
- **5** Locate the **Constitutive Relation D-E** section. In the ε_r text field, type 3.
- 6 Right-click Component I (compl)>Electrostatics (es)>Charge Conservation I and choose Duplicate.

Charge Conservation 2

- I In the Model Builder window, click Charge Conservation 2.
- 2 In the Settings window for Charge Conservation, locate the Domain Selection section.
- **3** In the list, select **1**.
- 4 Click Remove from Selection.
- **5** Select Domain 2 only.
- **6** Locate the **Constitutive Relation D-E** section. In the $\varepsilon_{\mathbf{r}}$ text field, type 79.

V s

- I In the Physics toolbar, click Boundaries and choose Electric Potential.
- 2 In the Settings window for Electric Potential, type V_s in the Label text field.
- 3 Locate the Boundary Selection section. Click Paste Selection.
- **4** In the **Paste Selection** dialog box, type 1 in the **Selection** text field.
- 5 Click OK.

6 Right-click **V_s** and choose **Duplicate**.

V dr

- I In the Model Builder window, under Component I (compl)>Electrostatics (es) click V_s I.
- 2 In the Settings window for Electric Potential, type V_dr in the Label text field.
- 3 Locate the Boundary Selection section. Click Clear Selection.
- 4 Click Paste Selection.
- 5 In the Paste Selection dialog box, type 6 in the Selection text field.
- 6 Click OK.
- 7 In the Settings window for Electric Potential, locate the Electric Potential section.
- **8** In the V_0 text field, type V_dr.
- 9 Right-click **V_dr** and choose **Duplicate**.

V_g

- I In the Model Builder window, under Component I (compl)>Electrostatics (es) click V_dr I.
- 2 In the Settings window for Electric Potential, type V_g in the Label text field.
- 3 Locate the Boundary Selection section. Click Clear Selection.
- 4 Click Paste Selection.
- **5** In the **Paste Selection** dialog box, type 5 in the **Selection** text field.
- 6 Click OK.
- 7 In the Settings window for Electric Potential, locate the Electric Potential section.
- **8** In the V_0 text field, type V_g .

Space Charge Density 1

- I In the Physics toolbar, click **Domains** and choose Space Charge Density.
- 2 Select Domain 1 only.
- 3 In the Settings window for Space Charge Density, locate the Space Charge Density section.
- **4** In the ρ_v text field, type ch*F_const.
- 5 Right-click Space Charge Density I and choose Duplicate.

Space Charge Density 2

- I In the Model Builder window, click Space Charge Density 2.
- 2 In the Settings window for Space Charge Density, locate the Domain Selection section.
- 3 Click Clear Selection.

- 4 Select Domain 2 only.
- **5** Locate the **Space Charge Density** section. In the ρ_v text field, type (cp-cn)*F_const.

MESH I

In the Model Builder window, under Component I (compl) right-click Mesh I and choose Edit Physics-Induced Sequence.

Size 1

- I In the Model Builder window, expand the Component I (compl)>Mesh I> Free Triangular I node.
- 2 Right-click Free Triangular I and choose Size.
- 3 In the Settings window for Size, locate the Geometric Entity Selection section.
- 4 From the Geometric entity level list, choose Domain.
- 5 Click Paste Selection.
- 6 In the Paste Selection dialog box, type 1 in the Selection text field.
- 7 Click OK.
- 8 In the Settings window for Size, locate the Element Size section.
- **9** Click the **Custom** button.
- 10 Locate the Element Size Parameters section.
- II Select the Maximum element size check box. In the associated text field, type 1e-7[m].

Distribution I

- I In the Model Builder window, right-click Free Triangular I and choose Distribution.
- 2 In the Settings window for Distribution, locate the Boundary Selection section.
- 3 Click Paste Selection.
- 4 In the Paste Selection dialog box, type 5 in the Selection text field.
- 5 Click OK.
- 6 In the Settings window for Distribution, locate the Distribution section.
- 7 In the Number of elements text field, type 500.
- 8 Right-click Distribution I and choose Duplicate.

Distribution 2

- I In the Model Builder window, click Distribution 2.
- 2 In the Settings window for Distribution, locate the Boundary Selection section.
- 3 Click Clear Selection.

- 4 Click Paste Selection.
- 5 In the Paste Selection dialog box, type 1 6 in the Selection text field.
- 6 Click OK.
- 7 In the Settings window for Distribution, locate the Distribution section.
- 8 In the Number of elements text field, type 100.

Boundary Layers 1

In the Mesh toolbar, click Boundary Layers.

Boundary Layer Properties

- I In the Model Builder window, click Boundary Layer Properties.
- 2 In the Settings window for Boundary Layer Properties, locate the Boundary Selection section.
- 3 Click Paste Selection.
- 4 In the Paste Selection dialog box, type 4 5 in the Selection text field.
- 5 Click OK.
- 6 In the Settings window for Boundary Layer Properties, locate the Layers section.
- 7 In the Stretching factor text field, type 1.05.
- 8 In the Model Builder window, right-click Mesh I and choose Build All.

STUDY I

Step 1: Stationary

- I In the Model Builder window, under Study I click Step I: Stationary.
- 2 In the Settings window for Stationary, click to expand the Study Extensions section.
- 3 Select the Auxiliary sweep check box.
- 4 Click + Add.
- **5** In the table, click to select the cell at row number 1 and column number 2.
- **6** In the table, enter the following settings:

Parameter name	Parameter value list	Parameter unit
V_g (Gate electrode voltage)		V

- 7 Click Range.
- 8 In the Range dialog box, type 0 in the Start text field.
- 9 In the Step text field, type -0.1.

10 In the Stop text field, type -0.5.

II Click Replace.

12 In the Settings window for Stationary, locate the Study Extensions section.

13 Click + Add.

14 In the table, click to select the cell at row number 2 and column number 2.

I5 In the table, enter the following settings:

Parameter name	Parameter value list	Parameter unit
V_dr (Drain electrode Voltage)		V

16 From the Sweep type list, choose All combinations.

17 Click Range.

18 In the Range dialog box, type 0 in the Start text field.

19 In the Step text field, type -0.01.

20 In the Stop text field, type -0.5.

21 Click Replace.

22 In the **Home** toolbar, click **Compute**.

RESULTS

Cut Line 2D I

- I In the Results toolbar, click Cut Line 2D.
- 2 In the Settings window for Cut Line 2D, locate the Line Data section.
- 3 From the Line entry method list, choose Point and direction.
- 4 Find the Point subsection. In the x text field, type w dom/2.
- **5** Find the **Direction** subsection. In the **x** text field, type 0.
- **6** In the **y** text field, type 1.
- 7 Click Plot.

V-y

- I In the Results toolbar, click \sim ID Plot Group.
- 2 In the Settings window for ID Plot Group, type V-y in the Label text field.
- 3 Locate the Data section. From the Parameter selection (V_dr) list, choose First.

Line Grabh I

Right-click **V-y** and choose **Line Graph**.

V-y

From the Dataset list, choose Cut Line 2D 1.

Line Graph 1

- I In the Model Builder window, click Line Graph I.
- 2 In the Settings window for Line Graph, locate the y-Axis Data section.
- **3** In the **Expression** text field, type V.
- 4 In the V-y toolbar, click Plot.

 V_{-v}

In the Model Builder window, right-click V-y and choose Duplicate.

E-y

- I In the Model Builder window, under Results click V-y I.
- 2 In the Settings window for ID Plot Group, type E-y in the Label text field.
- 3 Locate the Legend section. From the Position list, choose Upper middle.

Line Graph 1

- I In the Model Builder window, expand the E-y node, then click Line Graph I.
- 2 In the Settings window for Line Graph, click Replace Expression in the upper-right corner of the y-Axis Data section. From the menu, choose Component I (compl)>Electrostatics> Electric>es.normE - Electric field norm - V/m.
- 3 Click to expand the **Legends** section. Select the **Show legends** check box.
- 4 In the E-y toolbar, click Plot.

E-y

In the Model Builder window, right-click E-y and choose Duplicate.

ch-y

- I In the Model Builder window, under Results click E-y I.
- 2 In the Settings window for ID Plot Group, type ch-y in the Label text field.

Line Grabh I

- I In the Model Builder window, expand the ch-y node, then click Line Graph I.
- 2 In the Settings window for Line Graph, locate the y-Axis Data section.
- **3** In the **Expression** text field, type ch.
- 4 In the ch-y toolbar, click Plot.
- 5 Click the y-Axis Log Scale button in the Graphics toolbar.

ch-y

In the Model Builder window, right-click ch-y and choose Duplicate.

cb-y

- I In the Model Builder window, under Results click ch-y I.
- 2 In the Settings window for ID Plot Group, type cp-y in the Label text field.

Line Graph 1

- I In the Model Builder window, expand the cp-y node, then click Line Graph I.
- 2 In the Settings window for Line Graph, locate the y-Axis Data section.
- **3** In the **Expression** text field, type cp.
- 4 In the cp-y toolbar, click Plot.

ср-у

In the Model Builder window, right-click cp-y and choose Duplicate.

cn-y

- I In the Model Builder window, under Results click cp-y I.
- 2 In the Settings window for ID Plot Group, type cn-y in the Label text field.

Line Grabh I

- I In the Model Builder window, expand the cn-y node, then click Line Graph I.
- 2 In the Settings window for Line Graph, locate the y-Axis Data section.
- 3 In the Expression text field, type cn.
- 4 In the cn-y toolbar, click Plot.

I dr-V dr

- I In the Home toolbar, click In Add Plot Group and choose ID Plot Group.
- 2 In the Settings window for ID Plot Group, type I_dr-V_dr in the Label text field.

Global I

- I Right-click I_dr-V_dr and choose Global.
- 2 In the Settings window for Global, locate the y-Axis Data section.
- **3** In the table, enter the following settings:

Expression	Unit	Description
I_dr	uA	Drain current

4 Locate the x-Axis Data section. From the Parameter list, choose Expression.

- 5 In the Expression text field, type -V_dr.
- 6 Click to expand the Legends section. Find the Include subsection. Clear the Description check box.
- 7 In the I_dr-V_dr toolbar, click Plot.

ADD STUDY

- I In the Home toolbar, click Add Study to open the Add Study window.
- 2 Go to the Add Study window.
- 3 Find the Studies subsection. In the Select Study tree, select General Studies>Stationary.
- 4 Click Add Study in the window toolbar.
- 5 In the Home toolbar, click Add Study to close the Add Study window.

STUDY 2_SWEEPING V_G

- I In the Model Builder window, click Study 2.
- 2 In the Settings window for Study, type Study 2_Sweeping V_g in the Label text field.
- 3 Locate the Study Settings section. Clear the Generate default plots check box.

Steb 1: Stationary

- I In the Model Builder window, under Study 2_Sweeping V_g click Step 1: Stationary.
- 2 In the Settings window for Stationary, locate the Study Extensions section.
- 3 Select the Auxiliary sweep check box.
- 4 Click + Add.
- **5** In the table, enter the following settings:

Parameter name	Parameter value list	Parameter unit
V_dr (Drain electrode Voltage)	-0.1	V

- 6 Click + Add.
- 7 In the table, enter the following settings:

Parameter name	Parameter value list	Parameter unit
V_g (Gate electrode voltage)		V

- 8 From the Sweep type list, choose All combinations.
- 9 Click Range.
- 10 In the Range dialog box, type 0 in the Start text field.

II In the Step text field, type -0.01.

12 In the Stop text field, type -0.5.

13 Click Replace.

14 In the Home toolbar, click **Compute**.

RESULTS

I dr-V dr

In the Model Builder window, under Results right-click I_dr-V_dr and choose Duplicate.

- I In the Model Builder window, under Results click I_dr-V_dr I.
- 2 In the Settings window for ID Plot Group, type I_dr-V_g in the Label text field.
- 3 Locate the Data section. From the Dataset list, choose Study 2_Sweeping V_g/ Solution 2 (sol2).

Global I

- I In the Model Builder window, expand the I_dr-V_g node, then click Global I.
- 2 In the Settings window for Global, locate the y-Axis Data section.
- **3** In the table, enter the following settings:

Expression	Unit	Description
I_dr	uA	Drain current

- 4 Locate the x-Axis Data section. In the Expression text field, type -V_g.
- 5 In the I_dr-V_g toolbar, click Plot.